

The MOSFET Amplifier (2)

Lecture 8

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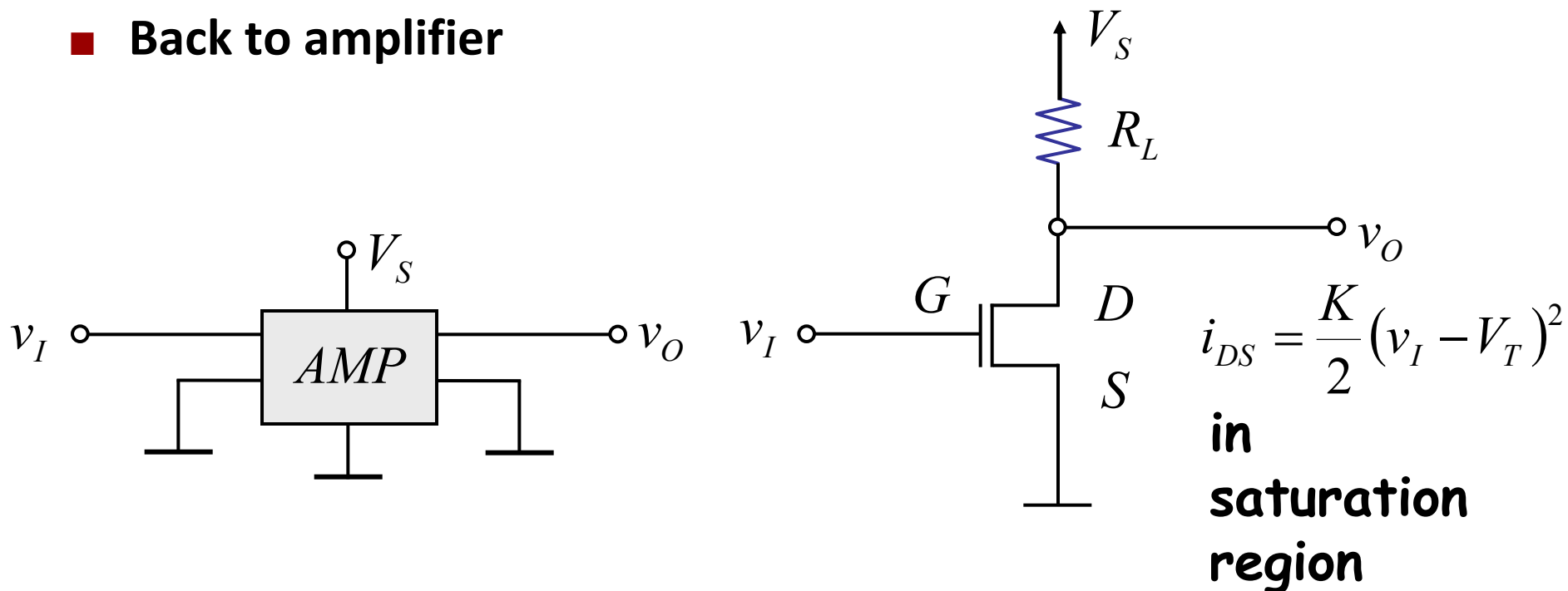
Outline

Textbook: 7.5, 7.6, 7.7

- **The MOSFET Amplifier**
- Large-Signal Analysis of the MOSFET Amplifier
- Operating Point Selection

The MOSFET Amplifier

■ Back to amplifier

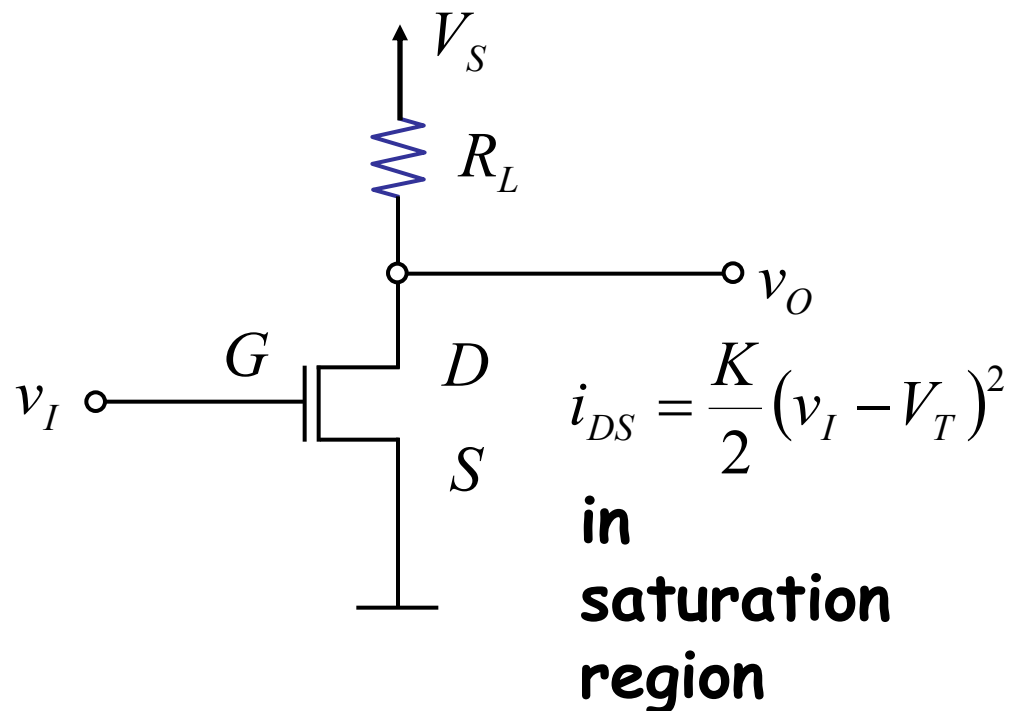


To ensure the MOSFET operates as a VCCS, we must operate it in its saturation region only. To do so, we promise to adhere to the “saturation discipline”

The MOSFET Amplifier

■ Back to amplifier

To ensure the MOSFET operates as a VCCS, we must operate it in its saturation region only. To do so, we promise to adhere to the “saturation discipline”



In other words, we will operate the amp circuit such that

$$v_{GS} \geq V_T \quad \text{and}$$

$$v_{DS} \geq v_{GS} - V_T$$

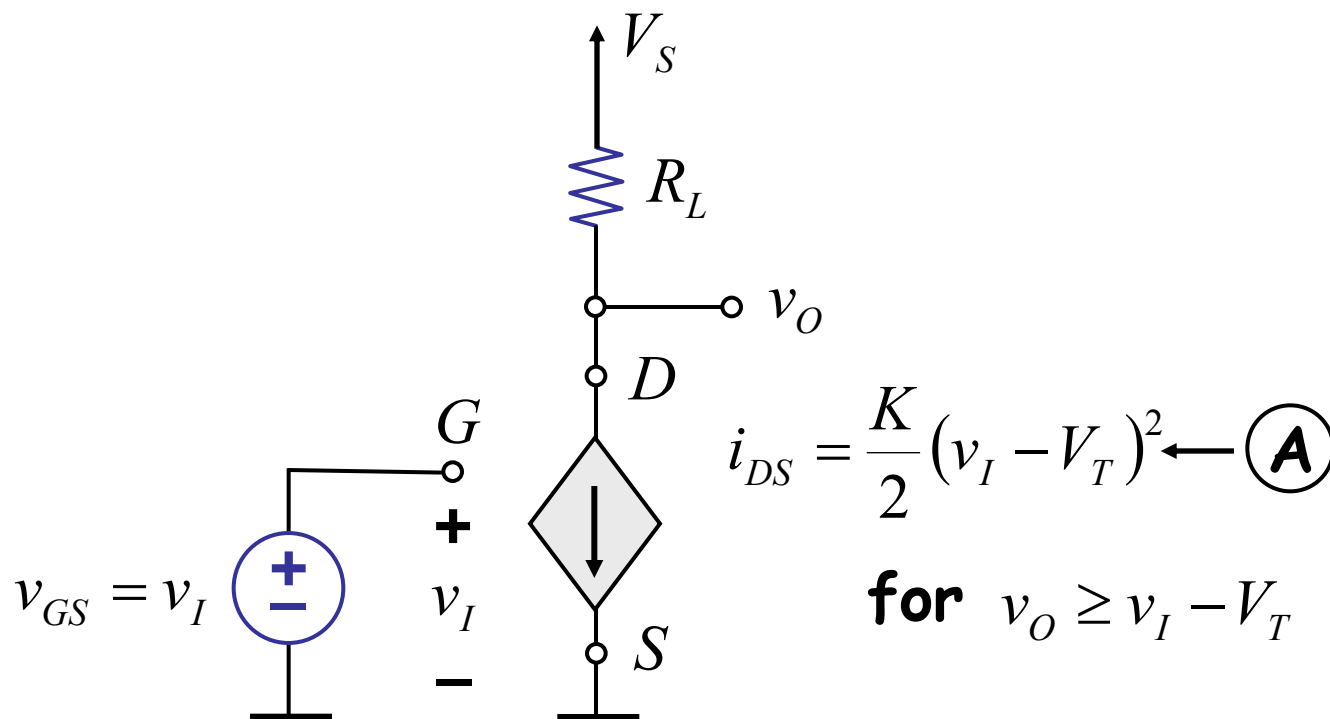
$$v_O \geq v_I - v_T$$

at all times.

The MOSFET Amplifier

- Let's analyze the circuit

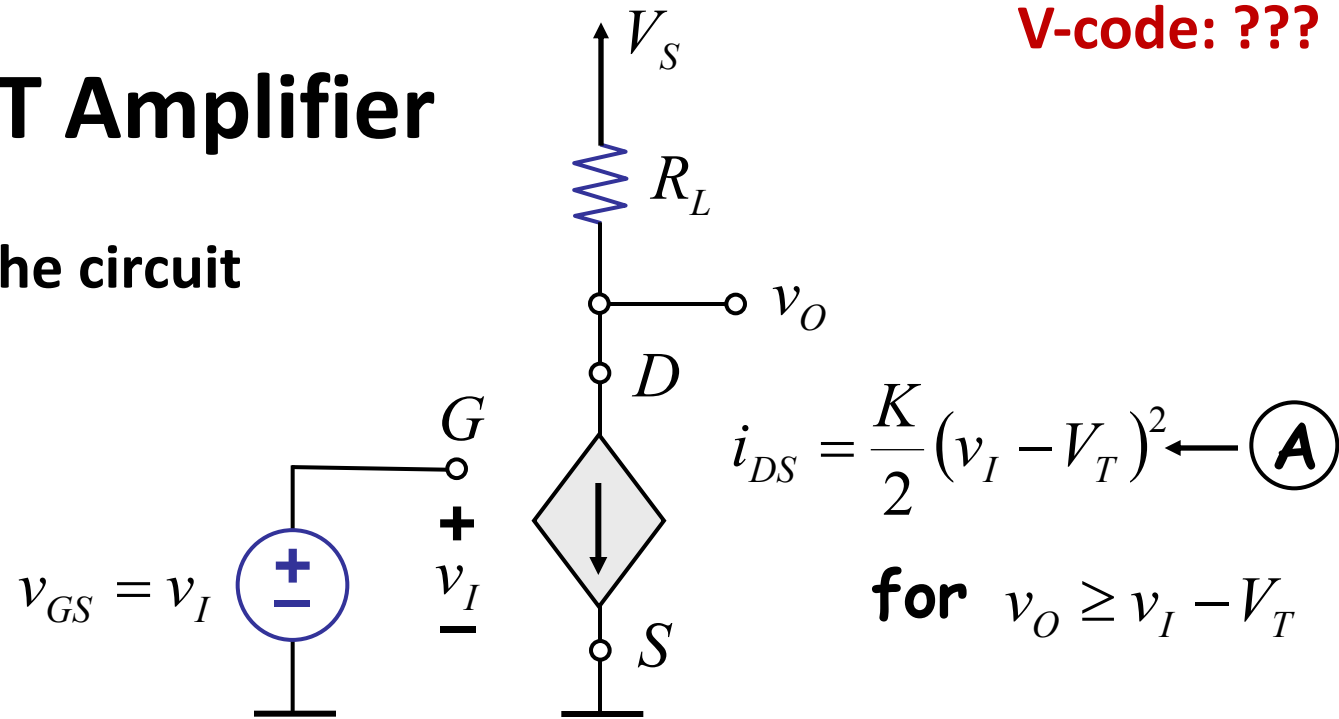
First, replace the MOSFET with its SCS model.



V-code: ???

The MOSFET Amplifier

■ Let's analyze the circuit



① **Analytical method:** v_O v_S v_I ($v_O = v_{DS}$ in our example)

$$v_O = V_S - i_{DS} R_L$$

or $v_O = V_S - \frac{K}{2} (v_I - V_T)^2 R_L$ **for** $v_I \geq V_T$
 $v_O \geq v_I - V_T$

$v_O = V_S$ **for** $v_I < V_T$

(MOSFET turns off)

The MOSFET Amplifier

- Let's analyze the circuit

② Graphical method v_O v_S v_I

From ① : $i_{DS} = \frac{K}{2} (v_I - V_T)^2$,

for $v_O \geq v_I - V_T$

\Downarrow

$$v_O \geq \sqrt{\frac{2i_{DS}}{K}}$$

\Downarrow

$$i_{DS} \leq \frac{K}{2} v_O^2$$

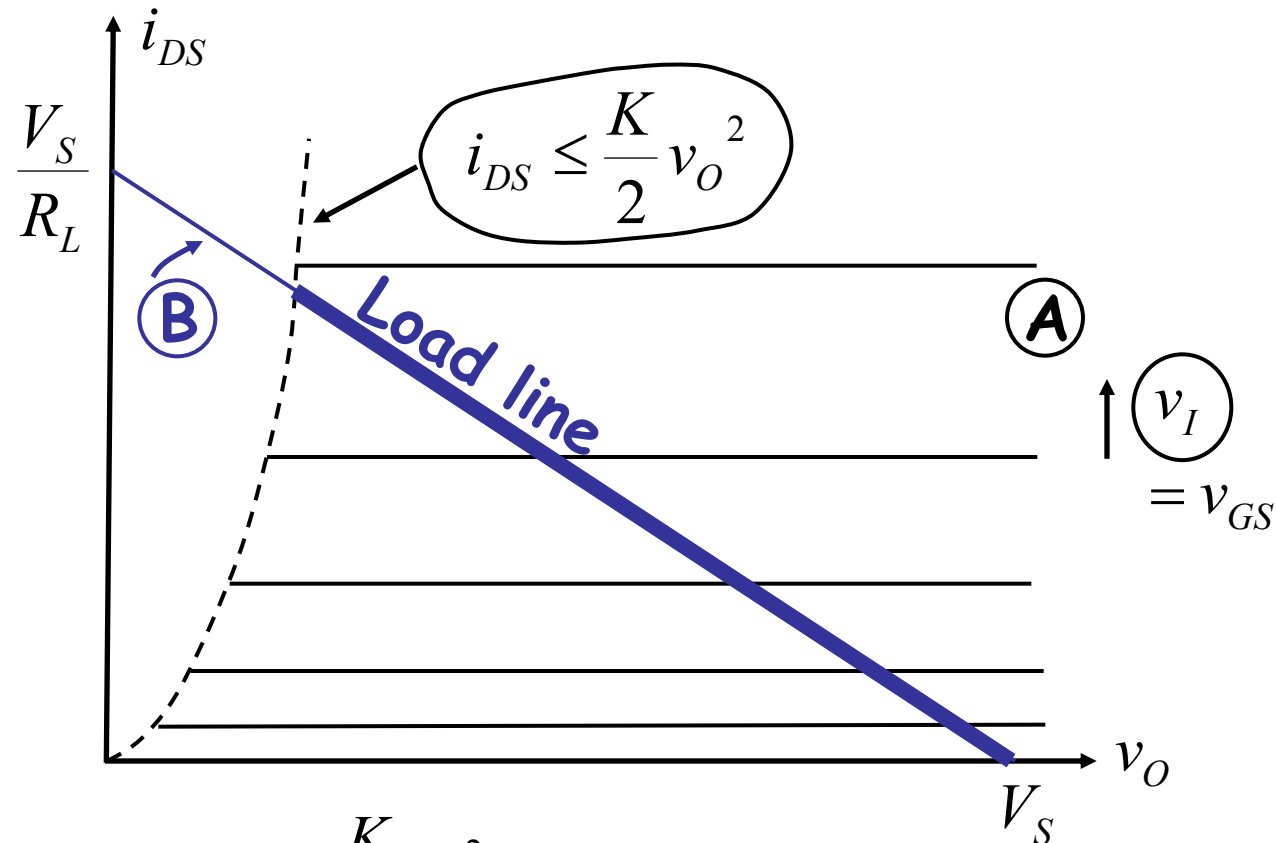
$$\textcircled{\text{B}} : i_{DS} = \frac{V_S}{R_L} - \frac{v_O}{R_L}$$

The MOSFET Amplifier

■ Let's analyze the circuit

② Graphical method

v_O v_S v_I



Ⓐ : $i_{DS} = \frac{K}{2} (v_I - V_T)^2$, for $i_{DS} \leq \frac{K}{2} v_O^2$

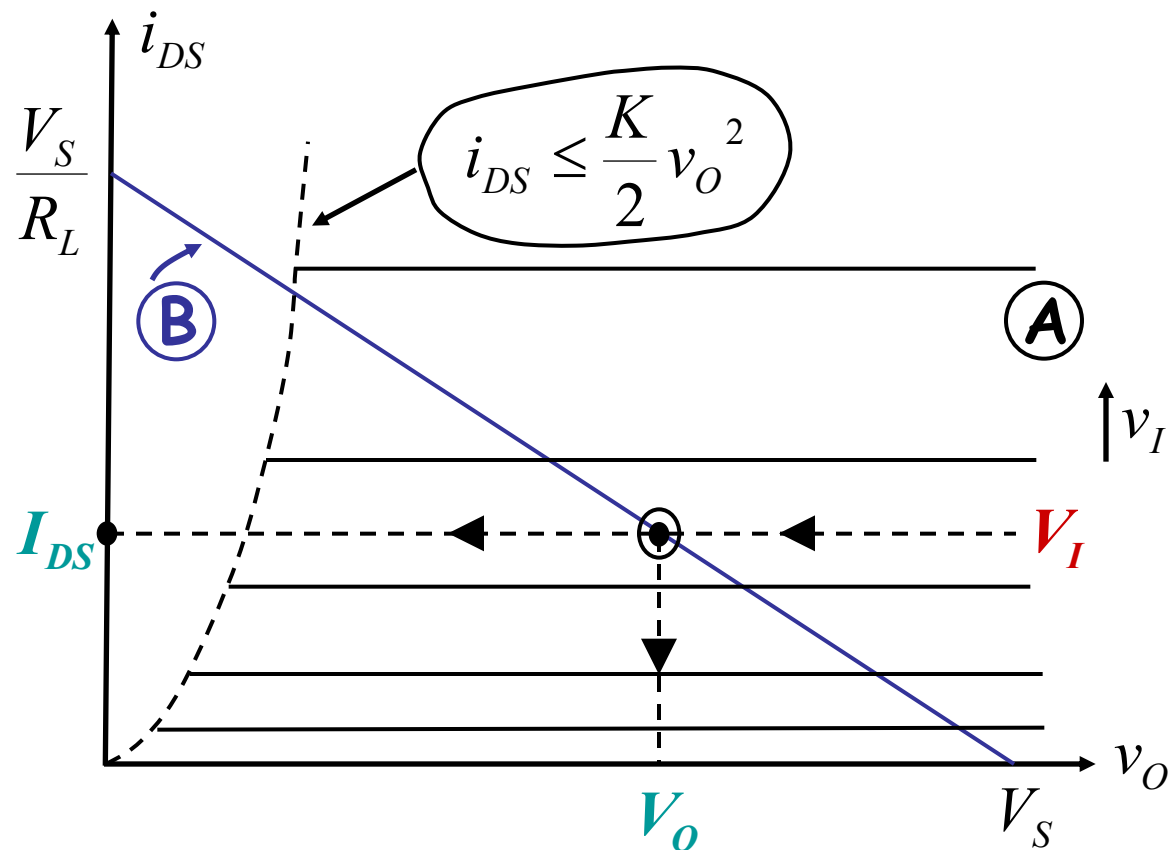
Ⓑ : $i_{DS} = \frac{V_S}{R_L} - \frac{v_O}{R_L}$

Constraints Ⓐ and Ⓑ must be met

The MOSFET Amplifier

■ Let's analyze the circuit

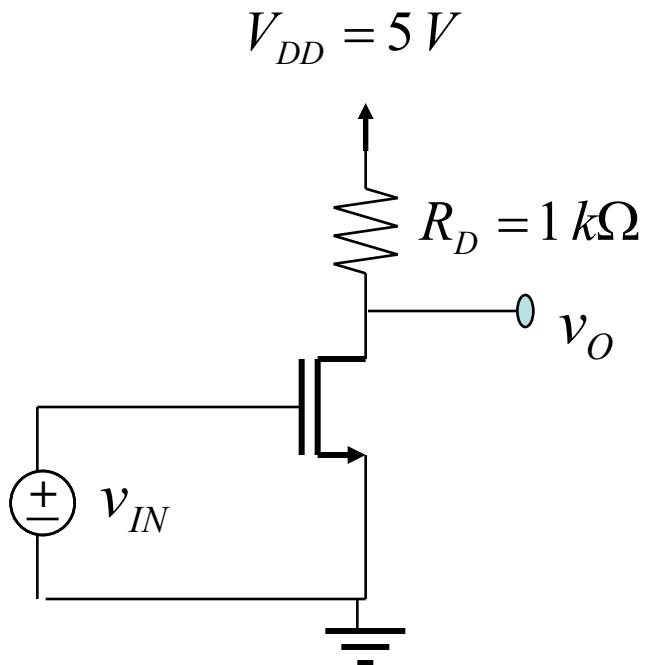
② Graphical method



Constraints (A) and (B) must be met.
Then, given V_I , we can find V_O , I_{DS} .

The MOSFET Amplifier

■ Example 7.7: A MOSFET Amplifier

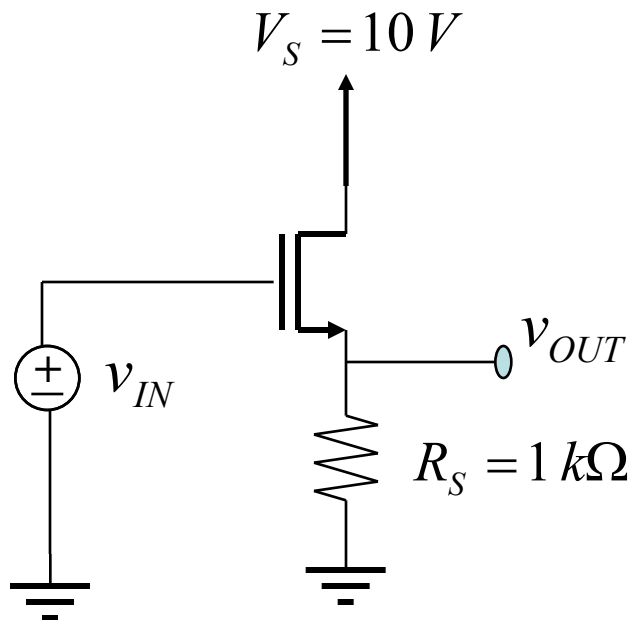


$$V_T = 0.8\text{ V}, K = 0.5\text{ mA/V}^2$$

$$v_{in} = 2.5\text{ V}, v_o = ?$$

The MOSFET Amplifier

■ Example 7.8: A MOSFET Source-Follower Circuit

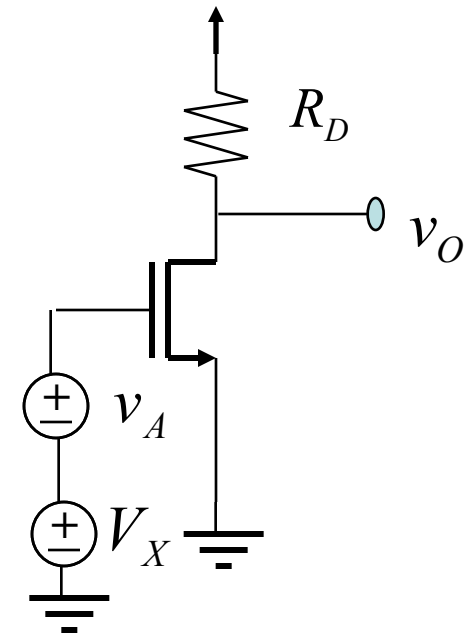
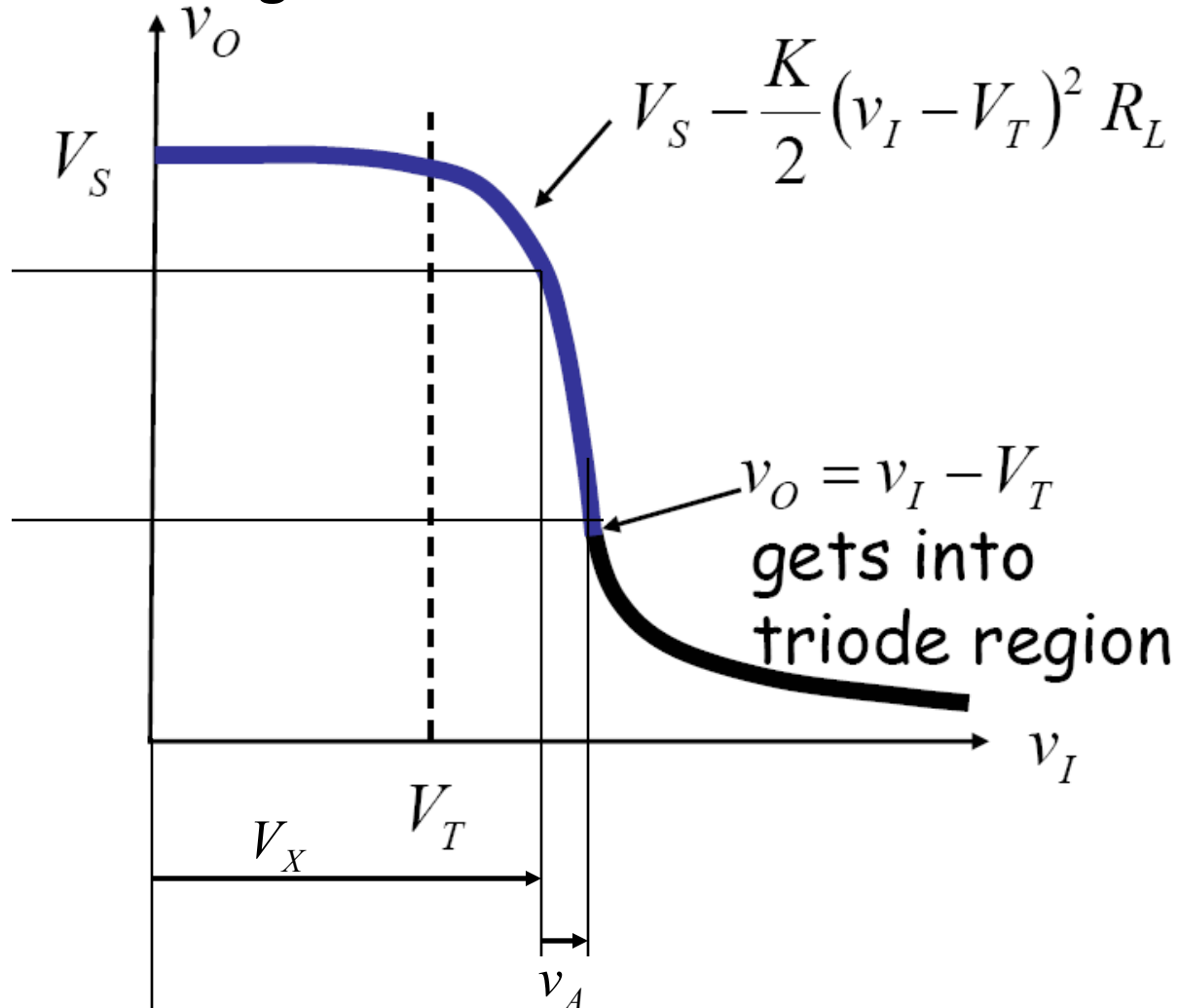


$$V_T = 1\text{ V}, K = 2\text{ mA/V}^2$$

$$v_{in} = 2\text{ V}, v_o = ?, i_D = ?$$

The MOSFET Amplifier

■ Biasing the Circuit



Outline

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Large-Signal Analysis

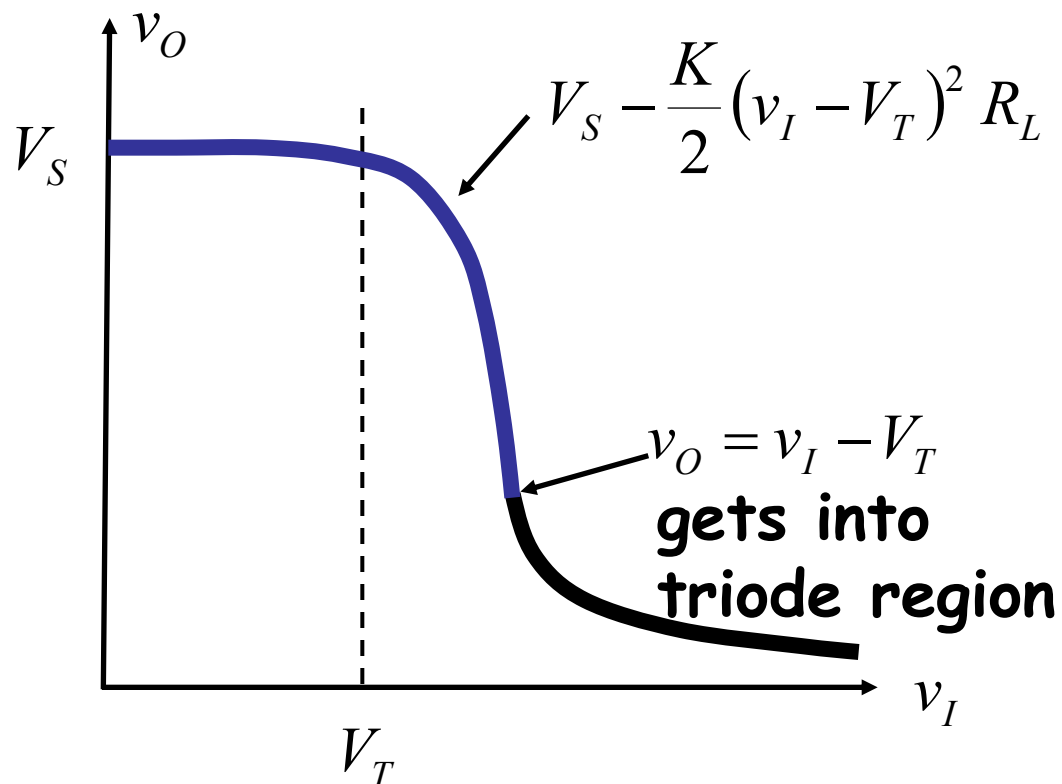
- Large signal analysis of amplifier
(under Saturation Discipline)

① v_O versus v_I

② Valid input operating range and
valid output operating range

Large-Signal Analysis

① v_O versus v_I

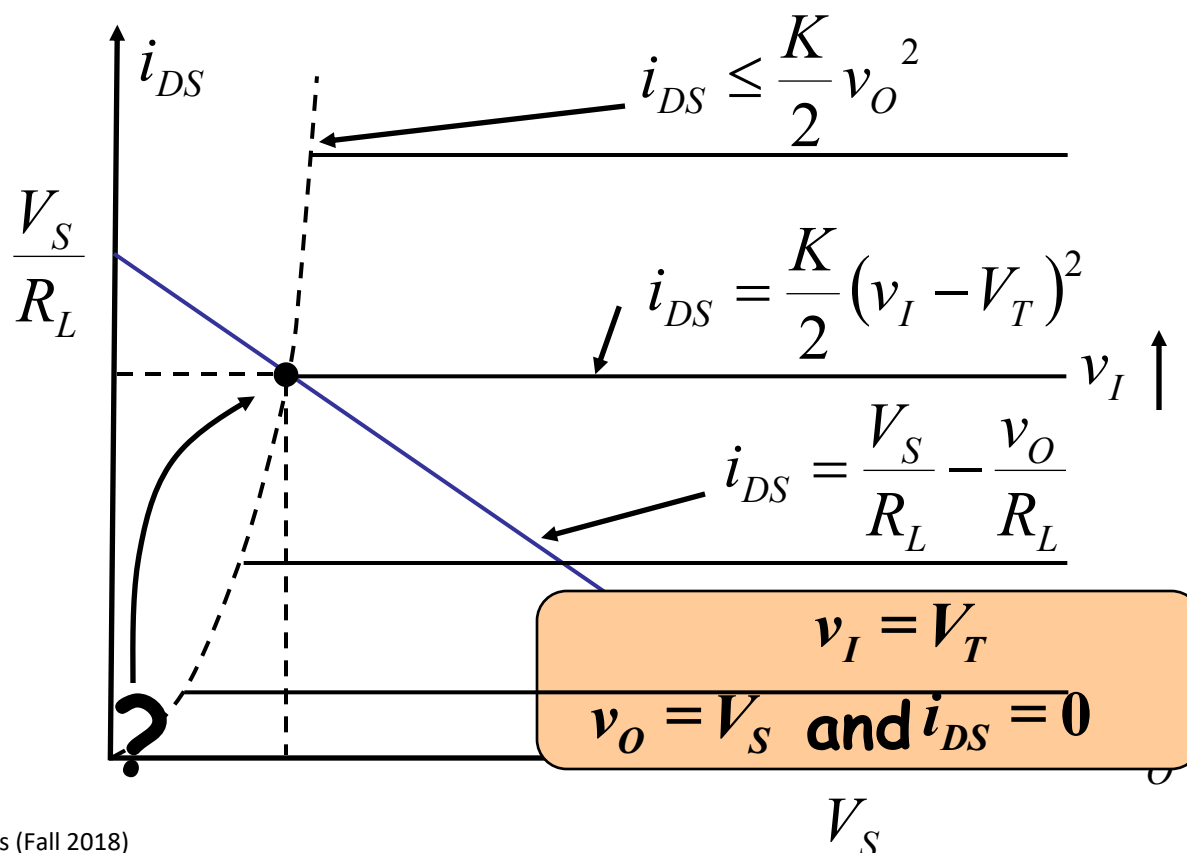


Large-Signal Analysis

Our
Constraints

$$\begin{aligned} v_I &\geq V_T \\ v_O &\geq v_I - V_T \end{aligned} \longrightarrow i_{DS} \leq \frac{K}{2} v_O^2$$

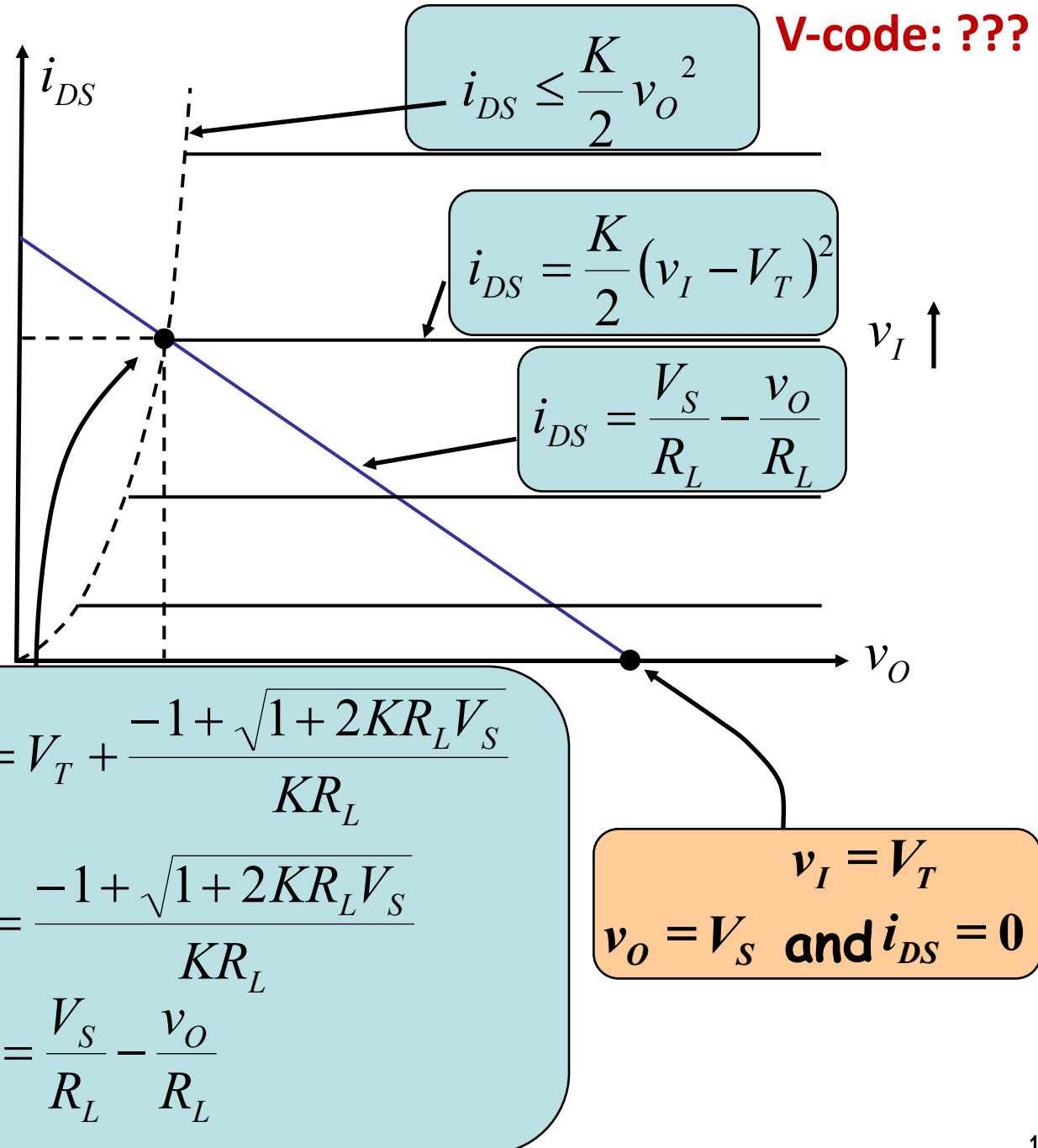
- ② What are valid operating ranges under the saturation discipline?



Large-Signal Analysis

V-code: ???

② What are valid operating ranges under the saturation discipline?



Large-Signal Analysis

■ Large-Signal Analysis: Summary

① v_O versus v_I

$$v_O = V_S - \frac{K}{2} (v_I - V_T)^2 R_L$$

② Valid operating ranges under the saturation discipline?

Valid input range:

$$v_I: \quad V_T \quad \text{to} \quad V_T + \frac{-1 + \sqrt{1 + 2KR_L V_S}}{KR_L}$$

corresponding output range:

$$v_O: \quad V_S \quad \text{to} \quad \frac{-1 + \sqrt{1 + 2KR_L V_S}}{KR_L}$$